## Designer's™ Data Sheet NPN Silicon Power Transistor High Voltage SWITCHMODE ${ }^{\text {m }}$ Series

Designed for use in electronic ballast (light ballast) and in Switchmode Power supplies up to 50 Watts. Main features include:

- Improved Efficiency Due to:
- Low Base Drive Requirements (High and Flat DC Current Gain hFE)
- Low Power Losses (On-State and Switching Operations)
- Fast Switching: $\mathrm{t}_{\mathrm{f}}=100 \mathrm{~ns}$ (typ) and $\mathrm{t}_{\mathrm{si}}=3.2 \mu \mathrm{~s}$ (typ)
$@ \mathrm{I}_{\mathrm{C}}=2.0 \mathrm{~A}, \mathrm{I}_{\mathrm{B}} 1=\mathrm{I}_{\mathrm{B}}=0.4 \mathrm{~A}$
- Full Characterization at $125^{\circ} \mathrm{C}$
- Tight Parametric Distributions Consistent Lot-to-Lot
- BUL45F, Case 221D, is UL Recognized at 3500 VRMS: File \#E69369


## MAXIMUM RATINGS

| Rating | Symbol | BUL45 | BUL45F | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Collector-Emitter Sustaining Voltage | $\mathrm{V}_{\text {CEO }}$ | 400 |  | Vdc |
| Collector-Emitter Breakdown Voltage | $\mathrm{V}_{\text {CES }}$ | 700 |  | Vdc |
| Emitter-Base Voltage | VEBO | 9.0 |  | Vdc |
| $\begin{array}{r} \hline \text { Collector Current — Continuous } \\ \text { —Peak(1) } \end{array}$ | $\begin{aligned} & \text { IC } \\ & \text { ICM } \end{aligned}$ | $\begin{aligned} & 5.0 \\ & 10 \end{aligned}$ |  | Adc |
| Base Current | IB | 2.0 |  | Adc |
| RMS Isolated Voltage(2) Test No. 1 Per Fig. 22a <br> (for 1 sec, R.H. $<30 \%$, Test No. 2 Per Fig. 22b <br> $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ ) Test No. 3 Per Fig. 22c | VISOL | - | $\begin{aligned} & 4500 \\ & 3500 \\ & 1500 \end{aligned}$ | Volts |
| Total Device Dissipation $\left(T_{\mathrm{C}}=25^{\circ} \mathrm{C}\right)$ <br> Derate above $25^{\circ} \mathrm{C}$  | $\mathrm{P}_{\mathrm{D}}$ | $\begin{aligned} & 75 \\ & 0.6 \end{aligned}$ | $\begin{gathered} \hline 35 \\ 0.28 \end{gathered}$ | Watts W/ ${ }^{\circ} \mathrm{C}$ |
| Operating and Storage Temperature | TJ, $\mathrm{T}_{\text {stg }}$ | -65 | 150 | ${ }^{\circ} \mathrm{C}$ |

THERMAL CHARACTERISTICS

| Rating | Symbol | MJE18006 | MJF18006 | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Thermal Resistance — Junction to Case | $R_{\text {日JC }}$ | 1.65 | 3.55 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| - Junction to Ambient | R $_{\text {өJA }}$ | 62.5 | 62.5 |  |

*Motorola Preferred Device

## POWER TRANSISTOR

 5.0 AMPERES 700 VOLTS 35 and 75 WATTS

BUL45 CASE 221A-06 TO-220AB


BUL45F
CASE 221D-02
ISOLATED TO-220 TYPE UL RECOGNIZED

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |

OFF CHARACTERISTICS

| Collector-Emitter Sustaining Voltage ( $\mathrm{I}_{\text {C }}=100 \mathrm{~mA}, \mathrm{~L}=25 \mathrm{mH}$ ) | $\mathrm{V}_{\text {CEO }}$ (sus) | 400 | - | - | Vdc |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Collector Cutoff Current ( $\mathrm{V}_{\mathrm{CE}}=$ Rated $\mathrm{V}_{\mathrm{CEO}}$, $\mathrm{I}_{\mathrm{B}}=0$ ) | ICEO | - | - | 100 | $\mu \mathrm{Adc}$ |
| Collector Cutoff Current ( $\mathrm{V}_{\mathrm{CE}}=$ Rated $\mathrm{V}_{\mathrm{CES}}, \mathrm{V}_{\mathrm{EB}}=0$ ) $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | ICES |  |  | $\begin{gathered} 10 \\ 100 \end{gathered}$ | $\mu \mathrm{Adc}$ |
| Emitter Cutoff Current ( $\mathrm{V}_{\mathrm{EB}}=9.0 \mathrm{Vdc}$, $\mathrm{IC}=0$ ) | IEBO | - | - | 100 | $\mu \mathrm{Adc}$ |

(1) Pulse Test: Pulse Width $=5.0 \mathrm{~ms}$, Duty Cycle $\leq 10 \%$.
(continued)
(2) Proper strike and creepage distance must be provided.

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Designer's Data for "Worst Case" Conditions - The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves - representing boundaries on device characteristics - are given to facilitate "worst case" design.
Preferred devices are Motorola recommended choices for future use and best overall value.

## REV 2

ELECTRICAL CHARACTERISTICS - continued ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| ON CHARACTERISTICS |  |  |  |  |  |
| Base-Emitter Saturation Voltage ( $\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=0.2 \mathrm{Adc}$ ) $\left(I_{C}=2.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=0.4 \mathrm{Adc}\right)$ | $\mathrm{V}_{\mathrm{BE} \text { (sat) }}$ | - | $\begin{aligned} & \hline 0.84 \\ & 0.89 \end{aligned}$ | $\begin{gathered} \hline 1.2 \\ 1.25 \end{gathered}$ | Vdc |
| Collector-Emitter Saturation Voltage $\left(\mathrm{IC}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=0.2 \mathrm{Adc}\right)$ $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{V}_{\text {CE }}$ (sat) | - | $\begin{aligned} & 0.175 \\ & 0.150 \end{aligned}$ | $\stackrel{0.25}{-}$ | Vdc |
| Collector-Emitter Saturation Voltage $\left(\mathrm{IC}=2.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=0.4 \mathrm{Adc}\right)$ $\left(\mathrm{T}^{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{V}_{\text {CE }}$ (sat) |  | $\begin{gathered} 0.25 \\ 0.275 \end{gathered}$ | $0.4$ | Vdc |
| $\begin{aligned} \left.\hline \text { DC Current Gain ( } \mathrm{I}_{\mathrm{C}}=0.3 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=2.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) & \end{aligned}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 14 \\ & \frac{14.0}{} \\ & 5.0 \\ & 10 \end{aligned}$ | $\begin{aligned} & - \\ & 32 \\ & 14 \\ & 12 \\ & 22 \end{aligned}$ | 34 <br> - <br> - | - |

## DYNAMIC CHARACTERISTICS

| Current Gain Bandwidth ( $\mathrm{l}_{\mathrm{C}}=0.5 \mathrm{Adc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}=1.0 \mathrm{MHz}$ ) |  |  |  | $\mathrm{f}^{\text {T }}$ | - | 12 | - | MHz |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Capacitance ( $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}$ ) |  |  |  | $\mathrm{C}_{\text {ob }}$ | - | 50 | 75 | pF |
| Input Capacitance ( $\mathrm{V}_{\mathrm{EB}}=8.0 \mathrm{Vdc}$ ) |  |  |  | $\mathrm{C}_{\mathrm{ib}}$ | - | 920 | 1200 | pF |
| Dynamic Saturation Voltage: <br> Determined $1.0 \mu \mathrm{~s}$ and $3.0 \mu \mathrm{~s}$ respectively after rising ${ }_{\mathrm{B}}^{\mathrm{B}} 1$ reaches $90 \%$ of final $l_{B 1}$ (see Figure 18) | $\begin{aligned} & (\mathrm{I} \mathrm{C}=1.0 \mathrm{Adc} \\ & \mathrm{I}_{1} 1=100 \mathrm{mAdc} \\ & \left.\mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V}\right) \end{aligned}$ | 1.0 $\mu \mathrm{s}$ | $\left(T^{C}=125^{\circ} \mathrm{C}\right)$ $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{V}_{\mathrm{CE}}$ (Dyn sat) | - - - | $\begin{gathered} \hline 1.75 \\ 4.4 \\ \hline 0.5 \\ 1.0 \end{gathered}$ | - | Vdc |
|  | $\begin{aligned} & (\mathrm{IC}=2.0 \mathrm{Adc} \\ & \mathrm{I}_{\mathrm{B} 1}=400 \mathrm{mAdc} \\ & \left.\mathrm{~V}_{\mathrm{Cc}}=300 \mathrm{~V}\right) \end{aligned}$ | 1.0 $\mu \mathrm{s}$ | $\left(T \mathrm{C}=125^{\circ} \mathrm{C}\right)$ $\left(\mathrm{T}^{\text {C }}=125^{\circ} \mathrm{C}\right)$ |  | - - - | $\begin{gathered} \hline 1.85 \\ 6.0 \\ \hline 0.5 \\ 1.0 \end{gathered}$ | - |  |

## SWITCHING CHARACTERISTICS: Resistive Load

| Turn-On Time | $\begin{aligned} & \text { (IC }=2.0 \text { Adc, } \mathrm{I}_{\mathrm{B} 1}=\mathrm{I}_{\mathrm{B} 2}=0.4 \mathrm{Adc} \\ & \text { Pulse Width }=20 \mu \mathrm{~s}, \quad\left(\mathrm{~T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ & \text { Duty Cycle }<20 \% \\ & \left.\mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V}\right) \end{aligned}$ | $\mathrm{t}_{0}$ |  | $\begin{gathered} 75 \\ 120 \end{gathered}$ | 110 | ns |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Turn-Off Time |  | $t_{\text {off }}$ | - | 2.8 3.5 |  | $\mu \mathrm{s}$ |

SWITCHING CHARACTERISTICS: Inductive Load (VCC $=15 \mathrm{Vdc}, \mathrm{L}_{\mathrm{C}}=200 \mu \mathrm{H}, \mathrm{V}_{\text {clamp }}=300 \mathrm{Vdc}$ )

| Fall Time | $\begin{aligned} & \left(\mathrm{IC}=2.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=0.4 \mathrm{Adc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=0.4 \mathrm{Adc}\right) \end{aligned}$ | $\left(\mathrm{T}_{\mathrm{C}} \mathrm{C}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\mathrm{fi}}$ | 70 | $\overline{200}$ | 170 - | ns |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Storage Time |  | $\left(\mathrm{T} \mathrm{C}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\text {si }}$ |  | - 4.2 |  | $\mu \mathrm{s}$ |
| Crossover Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | ${ }_{\text {t }}$ |  | $\begin{aligned} & 230 \\ & 400 \end{aligned}$ | 350 | ns |
| Fall Time | $\begin{aligned} & \left(\mathrm{I} \mathrm{C}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=100 \mathrm{mAdc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=0.5 \mathrm{Adc}\right) \end{aligned}$ | $\left(\mathrm{T} \mathrm{C}=125^{\circ} \mathrm{C}\right)$ | tfi |  | $\begin{aligned} & 110 \\ & 100 \end{aligned}$ | 150 | ns |
| Storage Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\text {si }}$ |  | $\begin{aligned} & 1.1 \\ & 1.5 \end{aligned}$ |  | $\mu \mathrm{s}$ |
| Crossover Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | ${ }_{t}$ |  | $\begin{aligned} & 170 \\ & 170 \end{aligned}$ | 250 | ns |
| Fall Time | $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=2.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=250 \mathrm{mAdc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=2.0 \mathrm{Adc}\right) \end{aligned}$ | $\left(T^{\prime} \mathrm{C}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\mathrm{fi}}$ | - | 80 | 120 | ns |
| Storage Time |  | $\left(T_{C}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\text {si }}$ | - | 0.6 | 0.9 | $\mu \mathrm{s}$ |
| Crossover Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | ${ }_{\text {t }}$ | - | 175 | 300 | ns |

## TYPICAL STATIC CHARACTERISTICS


${ }^{I}$ C, COLLECTOR CURRENT (AMPS)
Figure 1. DC Current Gain @ 1 Volt


Figure 3. Collector-Emitter Saturation Region


Figure 5. Base-Emitter Saturation Region


Figure 2. DC Current Gain at @ 5 Volts


Figure 4. Collector-Emitter Saturation Voltage


Figure 6. Capacitance

TYPICAL SWITCHING CHARACTERISTICS ( $\mathrm{IB} 2=\mathrm{IC} / 2$ for all switching)


Figure 7. Resistive Switching, $t_{o n}$


Figure 9. Inductive Storage Time, $\mathbf{t}_{\mathbf{s i}}$


Figure 11. Inductive Switching, $\mathrm{t}_{\mathrm{C}} \& \mathrm{t}_{\mathrm{f}}, \mathrm{I}_{\mathrm{C}} / \mathrm{I}_{\mathrm{B}}=5$


Figure 8. Resistive Switching, toff


Figure 10. Inductive Storage Time, $\mathbf{t}_{\mathbf{s i}}\left(\mathrm{h}_{\mathrm{FE}}\right)$


Figure 12. Inductive Switching, $\mathrm{t}_{\mathrm{C}}$ \& $\mathrm{t}_{\mathrm{f}}, \mathrm{I}_{\mathrm{C}} / \mathrm{I}_{\mathrm{B}}=10$

TYPICAL SWITCHING CHARACTERISTICS
( B B2 $=\mathrm{IC} / 2$ for all switching)


Figure 13. Inductive Fall Time, $\mathrm{t}_{\mathrm{f}}\left(\mathrm{h}_{\mathrm{FE}}\right)$


Figure 14. Crossover Time

GUARANTEED SAFE OPERATING AREA INFORMATION


Figure 15. Forward Bias Safe Operating Area


Figure 17. Forward Bias Power Derating


Figure 16. Reverse Bias Switching Safe Operating Area
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_{C}-V_{C E}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of Figure 15 is based on $\mathrm{T}_{\mathrm{C}}$ $=25^{\circ} \mathrm{C} ; \mathrm{T}_{\mathrm{J}(\mathrm{pk})}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to $10 \%$ but must be derated when $\mathrm{T}_{\mathrm{C}} \geq 25^{\circ} \mathrm{C}$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown in Figure 15 may be found at any case temperature by using the appropriate curve on Figure 17. $\mathrm{T}_{\mathrm{J}(\mathrm{pk})}$ may be calculated from the data in Figures 20 and 21. At any case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown. For inductive loads, high voltage and current must be sustained simultaneously during turn-off with the base-to-emitter junction re-verse-biased. The safe level is specified as a reverse-biased safe operating area (Figure 16). This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode.


Figure 18. Dynamic Saturation Voltage Measurements


Figure 19. Inductive Switching Measurements


Table 1. Inductive Load Switching Drive Circuit

## TYPICAL THERMAL RESPONSE



Figure 20. Typical Thermal Response ( $\mathrm{Z}_{\theta \mathrm{JC}}(\mathrm{t})$ ) for BUL45


Figure 21. Typical Thermal Response ( $\mathrm{Z}_{\theta \mathrm{JC}}(\mathrm{t})$ ) for BUL45F

## BUL45 BUL45F

The BUL45/BUL45F Bipolar Power Transistors were specially designed for use in electronic lamp ballasts. A circuit designed by Motorola applications was built to
demonstrate how well these devices operate. The circuit and detailed component list are provided below.


Components Lists

Q1 = Q2 = BUL45 Transistor
D1 $=1$ N4007 Rectifier
D2 $=1$ N5761 Rectifier
D3 $=\mathrm{D} 4=$ MUR150
D5 = D6 = MUR105
$D 7=D 8=D 9=D 10=1 \mathrm{~N} 400$
$\mathrm{CTN}=47 \Omega @ 25^{\circ} \mathrm{C}$
L = RM10 core, A1 = 400, B51 (LCC) 75 turns, wire $\varnothing=0.6 \mathrm{~mm}$
$\mathrm{T} 1=\mathrm{FT} 10$ toroid, T 4 A (LCC)
Primary: 4 turns
Secondaries: T1A: 4 turns
T1B: 4 turns

All resistors are $1 / 4$ Watt, $\pm 5 \%$
$\mathrm{R} 1=470 \mathrm{k} \Omega$
$\mathrm{R} 2=\mathrm{R} 3=47 \Omega$
R4 $=$ R5 $=1 \Omega$ (these resistors are optional, and might be replaced by a short circuit)
$\mathrm{C} 1=22 \mu \mathrm{~F} / 385 \mathrm{~V}$
$\mathrm{C} 2=0.1 \mu \mathrm{~F}$
$\mathrm{C} 3=10 \mathrm{nF} / 1000 \mathrm{~V}$
$\mathrm{C} 4=15 \mathrm{nF} / 1000 \mathrm{~V}$
$\mathrm{C} 5=\mathrm{C} 6=0.1 \mu \mathrm{~F} / 400 \mathrm{~V}$

NOTES:

1. Since this design does not include the line input filter, it cannot be used "as-is" in a practical industrial circuit.
2. The windings are given for a 55 Watt load. For proper operation they must be re-calculated with any other loads.

Figure 22. Application Example

## TEST CONDITIONS FOR ISOLATION TESTS*



MOUNTING INFORMATION**


Figure 23a. Screw-Mounted


Figure 23b. Clip-Mounted

Figure 23. Typical Mounting Techniques

## for Isolated Package

Laboratory tests on a limited number of samples indicate, when using the screw and compression washer mounting technique, a screw torque of 6 to 8 in • lbs is sufficient to provide maximum power dissipation capability. The compression washer helps to maintain a constant pressure on the package over time and during large temperature excursions.

Destructive laboratory tests show that using a hex head 4-40 screw, without washers, and applying a torque in excess of 20 in . lbs will cause the plastic to crack around the mounting hole, resulting in a loss of isolation capability.

Additional tests on slotted $4-40$ screws indicate that the screw slot fails between 15 to $20 \mathrm{in} \cdot \mathrm{lbs}$ without adversely affecting the package. However, in order to positively ensure the package integrity of the fully isolated device, Motorola does not recommend exceeding 10 in • Ibs of mounting torque under any mounting conditions.
** For more information about mounting power semiconductors see Application Note AN1040.

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